

# 1024 x 8-Bit n-MOS EEPROM with I<sup>2</sup>C-Bus Interface

**INA2586**

The INA2586 is a 8-Kbit (1024 x 8-bit) n-MOS floating gate electrically erasable programmable read only memory (EEPROM). IC works in systems with serial I<sup>2</sup>C-bus. Up to two INA2586 devices may be connected to the I<sup>2</sup>C-bus. The programming of the array is implemented by electron's tunneling. The programming voltage is generated on-chip, using a voltage multiplier. Device is functionally identical to the SDA2586, Siemens. IC are made in 8-pin DIP and 8-pin SOP.

## FEATURES

- ◆ Non-volatile storage of information during 10 years
- ◆ Single supply (U<sub>CC</sub>=4,75 B - 5,25 B)
- ◆ On-chip voltage multiplier
- ◆ On-chip generator of bulk biasing
- ◆ Serial input/output I<sup>2</sup>C-bus
- ◆ 10 000 ERASE/WRITE cycles per byte;
- ◆ Internal reprogramming (no external components)
- ◆ Duration of the ERASE/WRITE cycle is 15 ms
- ◆ Temperature range: 0 ÷ +70<sup>0</sup>C

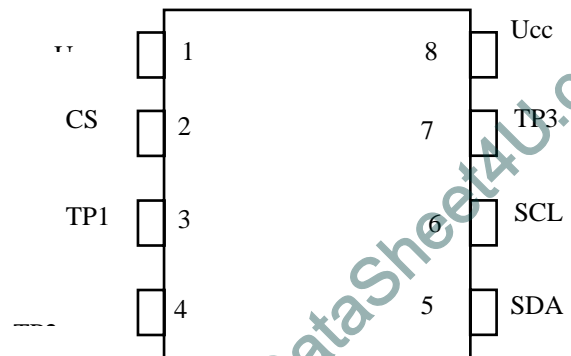
## ELECTRICAL CHARACTERISTICS

Parameter	Conditions	Symbol	Min.	Max
Supply current, mA	U <sub>CC</sub> =5.25 B	I <sub>CC0</sub>	-	20,0
Output low voltage (SDA), V	I <sub>OL</sub> =3 mA U <sub>CC</sub> =4.75B	U <sub>OL</sub>	-	0,4
High leakage current:				
-on output (SDA), μA	U <sub>OH</sub> =5,25 B	I <sub>LOH</sub>	-	10,0
-on inputs SCL, SDA, μA	U <sub>IH</sub> =5,25 B	I <sub>LIH</sub>	-	10,0
-on inputs CS, TP1, TP2, μA	U <sub>IH</sub> =5,25 B	I <sub>LIH</sub>	-	100,0
Input capacitance, pF	U <sub>I</sub> = 0 B	C <sub>I</sub>	-	10,0
Clock input frequency, kHz		f <sub>SCL</sub>	0	100
Reprogramming cycle time, ms	Erase and Write	t <sub>PROG</sub>	10,0	20,0
Erase of die cycle time, ms	U <sub>TP2</sub> = 5,0 B	t <sub>ER</sub>	-	20,0
The number of E/W cycles on 1 byte			10 000	-
Input high voltage:				
-inputs SDA, SCL, V		U <sub>IH</sub>	3,0	U <sub>CC</sub>
-inputs CS, TP1, TP2, V			4,5	U <sub>CC</sub>
Input low voltage:				
-inputs SDA, SCL, V		U <sub>IL</sub>	-	1,5
-inputs CS, TP1, TP2, V			-	0,2

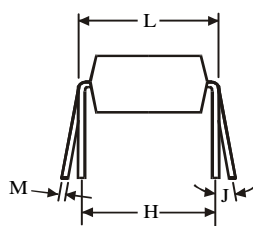
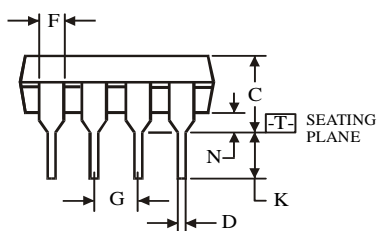
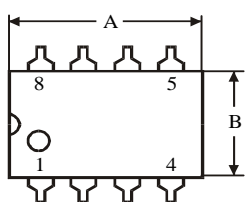
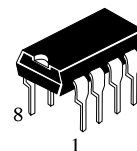
## PIN DESCRIPTION

SYMBOL	PIN	DESCRIPTION
Uss	1	GND
CS	2	Chip selection
TP1	3	Testing pin
TP2	4	Testing pin (0V - normal mode, 5V - chip erasing)
SDA	5	Informational line, input/output
SCL	6	Clock input
TP3	7	Testing pin, not connected
Ucc	8	Supply Voltage

## PIN ASSIGNMENT



**N SUFFIX PLASTIC DIP  
(MS - 001BA)**



$\oplus 0.25 (0.010) \text{M} \text{T}$

Symbol	Dimension, mm	
	MIN	MAX
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

**NOTES:**

- Dimensions "A", "B" do not include mold flash or protrusions.  
Maximum mold flash or protrusions 0.25 mm (0.010) per side.